

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	transistor and (gate near5 recess) and (schottky adj junction) and (pn adj junction adj diode)	USPAT; EPO; JPO; DERWENT	OR	OFF	2005/01/09 18:50
L2	1	transistor and (gate near10 recess) and (schottky adj junction) and (pn adj junction adj diode)	USPAT; EPO; JPO; DERWENT	OR	OFF	2005/01/09 18:51
L3	43	transistor and (schottky adj junction) and (pn adj junction adj diode)	USPAT; EPO; JPO; DERWENT	OR	OFF	2005/01/09 19:12
L4	9	3 and gate near5 insulating adj (film or layer)	USPAT; EPO; JPO; DERWENT	OR	OFF	2005/01/09 18:56
L5	34	3 not 4	USPAT; EPO; JPO; DERWENT	OR	OFF	2005/01/09 18:57